

Features

- Low forward voltage drop
- High reverse voltage
- Hermetic metal cases with ceramic insulators

Typical Applications

- All purpose high power rectifier diodes
- High power resistance welding equipment
- Non-controllable and half-controllable rectifiers
- Controlled rectifiers

$I_{F(AV)}$	2490 A
V_{RRM}	4300~5000 V
I_{FSM}	26 kA
I^2t	3380 $10^3 A^2S$



SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_J(^{\circ}C)$	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Double side cooled,	$T_C=85^{\circ}C$	150		2490	A
V_{RRM}	Repetitive peak reverse voltage	tp=10ms	150	4300		5000	V
I_{RRM}	Repetitive peak current	at V_{RRM}	150			150	mA
I_{FSM}	Surge forward current	10ms half sine wave $V_R=0.6V_{RRM}$	150			26	kA
I^2t	I^2t for fusing coordination					3380	$A^2s * 10^3$
V_{FO}	Threshold voltage		150			0.96	V
r_F	Forward slope resistance					0.17	$m\Omega$
V_{FM}	Peak forward voltage	$I_{FM}=3000A, F=34kN$	25			2.00	V
Q_{rr}	Recovery charge	$I_{FM}=2000A, tp=2000\mu s, di/dt=-20A/\mu s, V_R=50V$	150		4500		μC
$R_{th(j-c)}$	Thermal resistance Junction to case	At 180° sine double side cooled Clamping force 34kN				0.013	$^{\circ}C / W$
$R_{th(c-h)}$	Thermal resistance case to heatsink					0.0035	
F_m	Mounting force			27	32	34	kN
T_{stg}	Stored temperature			-40		160	$^{\circ}C$
W_t	Weight					820	g
Outline		ZT60cT65					

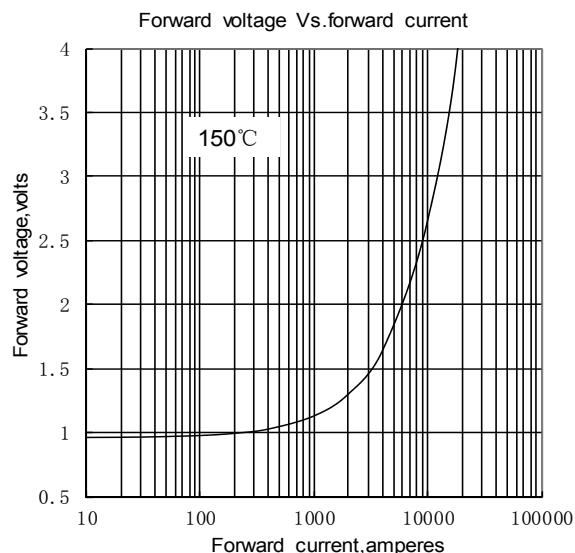


Fig.1

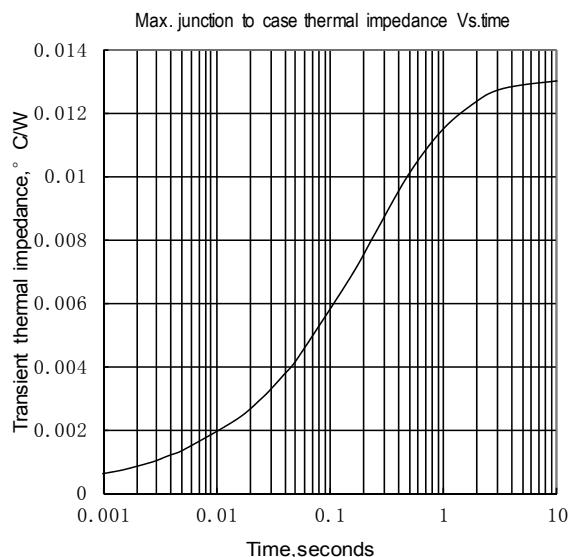


Fig.2

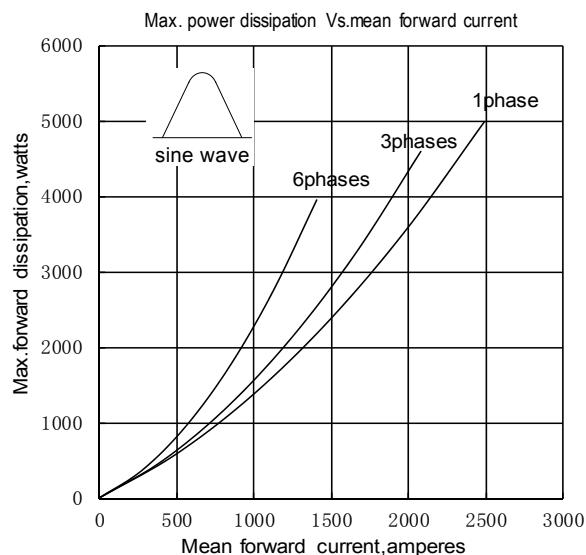


Fig.3

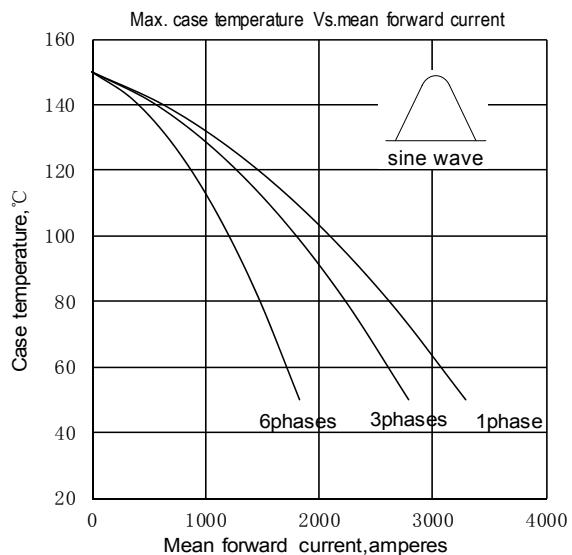


Fig.4

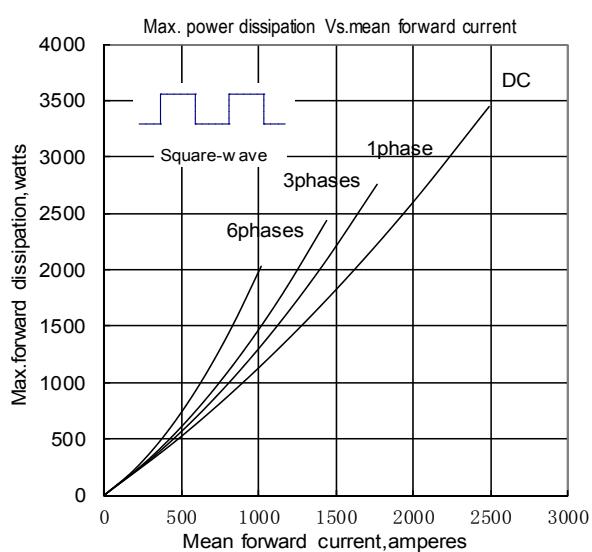


Fig.5

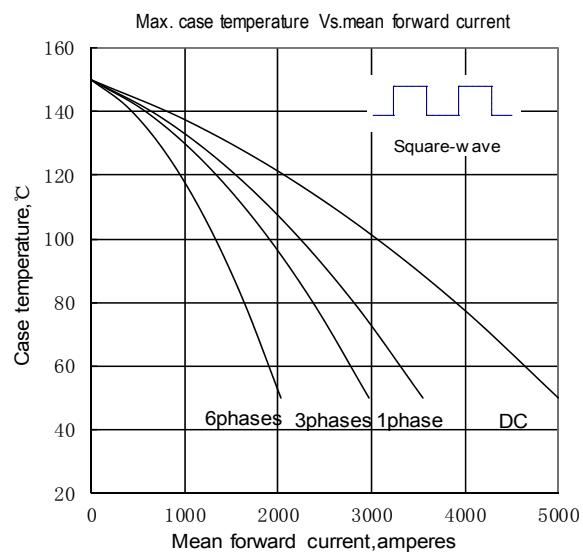


Fig.6

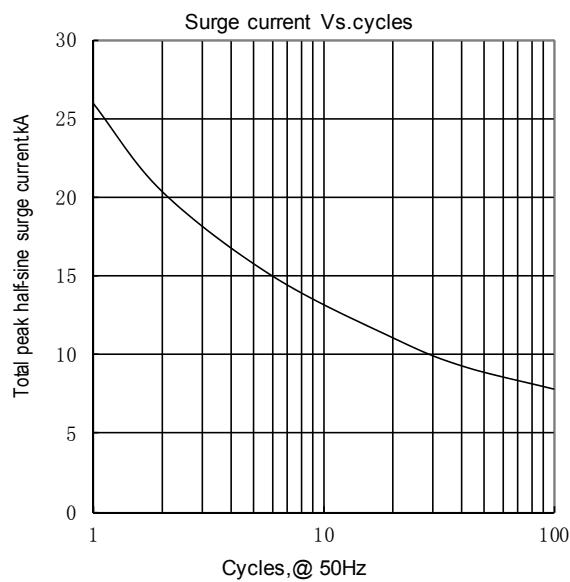


Fig.7

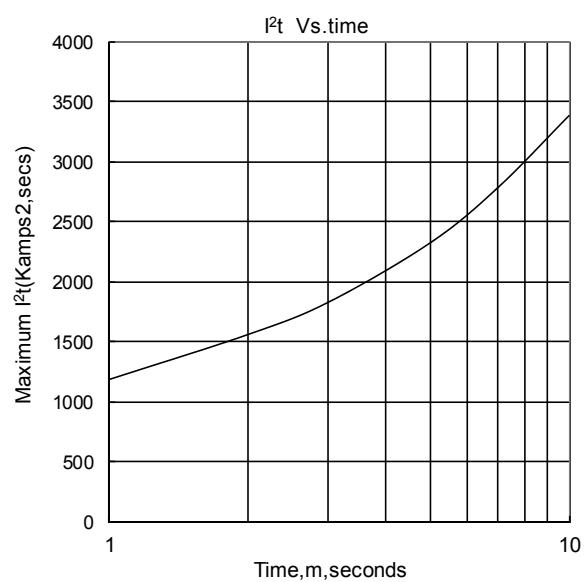


Fig.8

Outline: